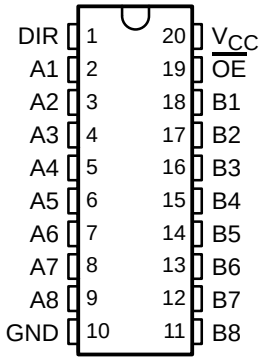
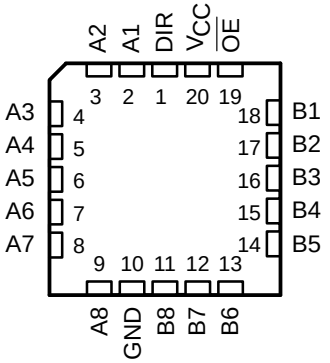
- **Inputs Are TTL-Voltage Compatible**
- ***EPIC***™ **(Enhanced-Performance Implanted CMOS) Process**
- **High Latch-Up Immunity Exceeds 250 mA Per JEDEC Standard JESD-17**
- **Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs**

SN54AHCT245 . . . J OR W PACKAGE
SN74AHCT245 . . . DB, DW, N, OR PW PACKAGE
(TOP VIEW)



SN54AHCT245 . . . FK PACKAGE
(TOP VIEW)



description

These octal bus transceivers are designed for asynchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements.

The ’AHCT245 allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending upon the logic level at the direction-control (DIR) input. The output-enable ($\overline{OE}$) input can be used to disable the device so that the buses are effectively isolated.

The SN54AHCT245 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AHCT245 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE

INPUTS		OPERATION
$\overline{OE}$	DIR	
L	L	B data to A bus
L	H	A data to B bus
H	X	Isolation

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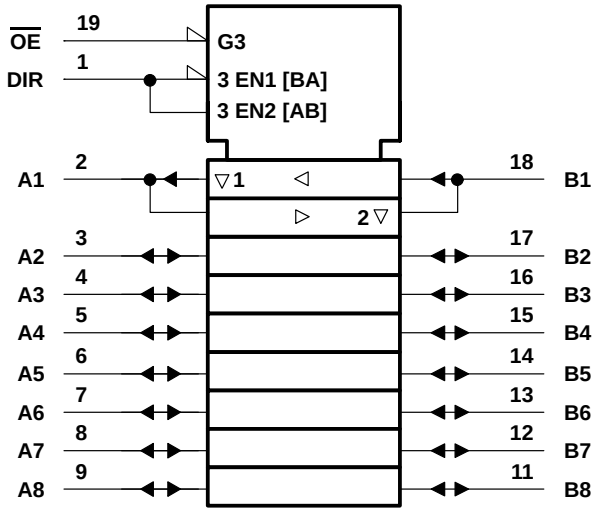
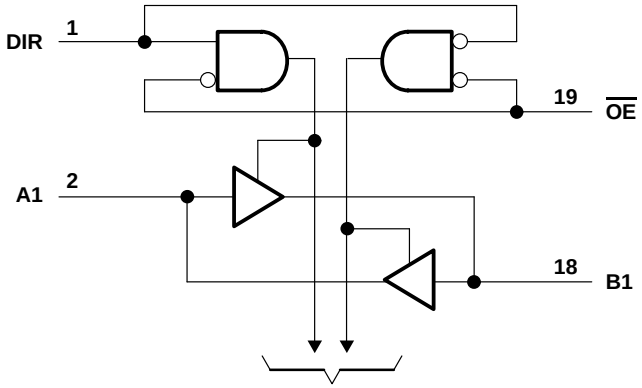
logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} . . . . . –0.5 V to 7 V
Input voltage range, V_I (see Note 1) . . . . . –0.5 V to 7 V
Output voltage range, V_O (see Note 1) . . . . . –0.5 V to V_{CC} + 0.5 V
Input clamp current, I_{IK} (V_I < 0 or V_I > V_{CC}) . . . . . –20 mA
Output clamp current, I_{OK} (V_O < 0 or V_O > V_{CC}) . . . . . –20 mA
Continuous output current, I_O (V_O = 0 to V_{CC}) . . . . . ±25 mA
Continuous current through V_{CC} or GND . . . . . ±75 mA
Maximum power dissipation at T_A = 55°C (in still air) (see Note 2): DB package . . . . . 0.6 W
DW package . . . . . 1.6 W
N package . . . . . 1.3 W
PW package . . . . . 0.7 W
Storage temperature range, T_{stg} . . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.

recommended operating conditions (see Note 3)

		SN54AHCT245		SN74AHCT245		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage	0	5.5	0	5.5	V
V_O	Output voltage	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current		–8		–8	mA
I_{OL}	Low-level output current		8		8	mA
$\Delta t/\Delta v$	Input transition rise or fall rate		20		20	ns/V
T_A	Operating free-air temperature	–55	125	–40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

ADVANCE INFORMATION

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	T_A = 25°C			SN54AHCT245		SN74AHCT245		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V_{OH}		I_{OH} = –50 μA	4.5 V	4.4	4.5		4.4		4.4		V
		I_{OH} = –8 mA		3.94			3.8		3.8		
V_{OL}		I_{OL} = 50 μA	4.5 V			0.1		0.1		0.1	V
		I_{OL} = 8 mA				0.36		0.44		0.44	
I_{OZ}	A or B inputs†	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5		±2.5	μA
I_I	$\overline{OE}$ or DIR	$V_I = V_{CC}$ or GND	5.5 V			±0.1		±1		±1	μA
I_{CC}		$V_I = V_{CC}$ or GND, I_O = 0	5.5 V			4		40		40	μA
ΔI_{CC}‡		One input at 3.4 V, Other inputs at V_{CC} or GND	5.5 V			1.35		1.5		1.5	mA
C_i	$\overline{OE}$ or DIR	$V_I = V_{CC}$ or GND	5 V		2.5	10				10	pF
C_{io}	A or B inputs	$V_I = V_{CC}$ or GND	5 V		4						pF

† For I/O ports, the parameter I_{OZ} includes the input leakage current.
‡ This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	SN54AHCT245					UNIT
				T_A = 25°C			MIN	MAX	
				MIN	TYP	MAX			
t_{PLH}*	A or B	B or A	C_L = 15 pF		4.5	7.7	1	8.5	ns
t_{PHL}*					4.5	7.7	1	8.5	
t_{PZH}*	$\overline{OE}$	A or B	C_L = 15 pF		8.9	13.8	1	15	ns
t_{PZL}*					8.9	13.8	1	15	
t_{PHZ}*	$\overline{OE}$	A or B	C_L = 15 pF		9.2	14.4	1	15.5	ns
t_{PLZ}*					9.2	14.4	1	15.5	
t_{PLH}	A or B	B or A	C_L = 50 pF		5.3	8.7	1	9.5	ns
t_{PHL}					5.3	8.7	1	9.5	
t_{PZH}	$\overline{OE}$	A or B	C_L = 50 pF		9.7	14.8	1	16	ns
t_{PZL}					9.7	14.8	1	16	
t_{PHZ}	$\overline{OE}$	A or B	C_L = 50 pF		10	15.4	1	16.5	ns
t_{PLZ}					10	15.4	1	16.5	

* On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	SN74AHCT245					UNIT
				T_A = 25°C			MIN	MAX	
				MIN	TYP	MAX			
t_{PLH}	A or B	B or A	C_L = 15 pF		4.5	7.7	1	8.5	ns
t_{PHL}					4.5	7.7	1	8.5	
t_{PZH}	$\overline{OE}$	A or B	C_L = 15 pF		8.9	13.8	1	15	ns
t_{PZL}					8.9	13.8	1	15	
t_{PHZ}	$\overline{OE}$	A or B	C_L = 15 pF		9.2	14.4	1	15.5	ns
t_{PLZ}					9.2	14.4	1	15.5	
t_{PLH}	A or B	B or A	C_L = 50 pF		5.3	8.7	1	9.5	ns
t_{PHL}					5.3	8.7	1	9.5	
t_{PZH}	$\overline{OE}$	A or B	C_L = 50 pF		9.7	14.8	1	16	ns
t_{PZL}					9.7	14.8	1	16	
t_{PHZ}	$\overline{OE}$	A or B	C_L = 50 pF		10	15.4	1	16.5	ns
t_{PLZ}					10	15.4	1	16.5	

output-skew characteristics, C_L = 50 pF (see Note 4)

PARAMETER		V_{CC}	SN74AHCT245				UNIT
			T_A = 25°C		MIN	MAX	
			MIN	MAX			
$t_{sk(o)}$	Output skew	5 V ± 0.5 V		1		1	ns

NOTE 4: Characteristics are determined during product characterization and ensured by design.

noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C (see Note 5)

PARAMETER		SN74AHCT245			UNIT
		MIN	TYP	MAX	
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}		4		V
$V_{IH(D)}$	High-level dynamic input voltage	2			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V

NOTE 5: Characteristics are determined during product characterization and ensured by design for surface-mount packages only.

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		TYP	UNIT
C_{pd}	Power dissipation capacitance per transceiver	No load,	f = 1 MHz	13	pF

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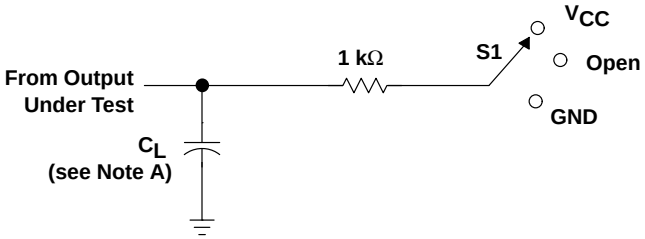
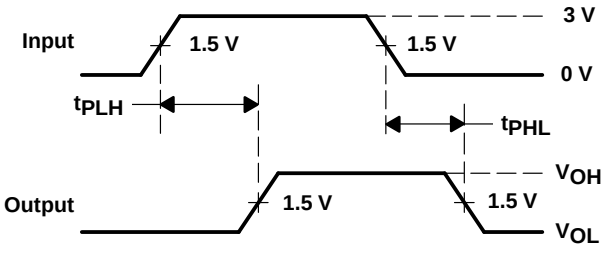
PARAMETER MEASUREMENT INFORMATION

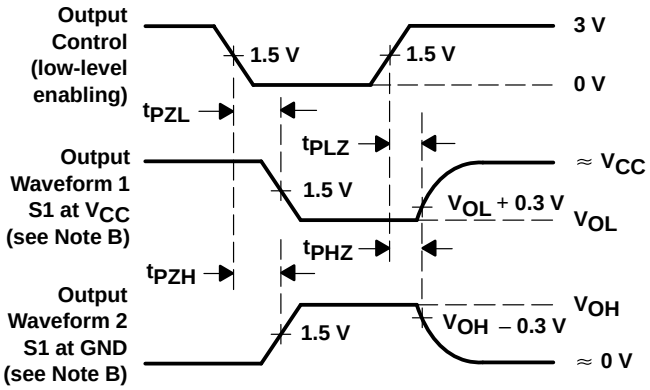


TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{CC}
t_{PHZ}/t_{PZH}	GND

LOAD CIRCUIT



VOLTAGE WAVEFORMS
DELAY TIMES



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_r = 3 ns, t_f = 3 ns.
D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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